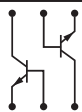


CMLT8099

SURFACE MOUNT
DUAL NPN SMALL SIGNAL
SILICON TRANSISTORS

PICOmini™



SOT-563 CASE

Central
Semiconductor Corp.

www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMLT8099 consists of two individual, isolated 8099 NPN silicon transistors, manufactured by the epitaxial planar process and epoxy molded in an SOT-563 surface mount package. This PICOmini™ device has been designed for small signal general purpose amplifier applications.

MARKING CODE: C89

FEATURES:

- Device is **Halogen Free** by design
- Current $I_C=500\text{mA}$
- Voltage $V_{CEO}=80\text{V}$

APPLICATIONS:

- Small signal general purpose amplifiers

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Collector-Base Voltage
Collector-Emitter Voltage
Emitter-Base Voltage
Continuous Collector Current
Power Dissipation
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL

V_{CBO} 80
 V_{CEO} 80
 V_{EBO} 6.0
 I_C 500
 P_D 350
 T_J, T_{stg} -65 to +150
 θ_{JA} 357

UNITS

V
V
V
mA
mW
 $^\circ\text{C}$
 $^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS PER TRANSISTOR: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=80\text{V}$		0.1	μA
I_{EBO}	$V_{BE}=6.0\text{V}$		0.1	μA
BV_{CBO}	$I_C=100\mu\text{A}$	80		V
BV_{CEO}	$I_C=10\text{mA}$	80		V
BV_{EBO}	$I_E=10\mu\text{A}$	6.0		V
$V_{CE(SAT)}$	$I_C=100\text{mA}, I_B=5.0\text{mA}$		0.4	V
$V_{CE(SAT)}$	$I_C=100\text{mA}, I_B=10\text{mA}$		0.3	V
$V_{BE(ON)}$	$V_{CE}=5.0\text{V}, I_C=10\text{mA}$	0.6	0.8	V
h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}$	100	300	
h_{FE}	$V_{CE}=5.0\text{V}, I_C=10\text{mA}$	100		
h_{FE}	$V_{CE}=5.0\text{V}, I_C=100\text{mA}$	75		
f_T	$V_{CE}=5.0\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	150		MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$		6.0	pF
C_{ib}	$V_{BE}=0.5\text{V}, I_C=0, f=1.0\text{MHz}$		25	pF

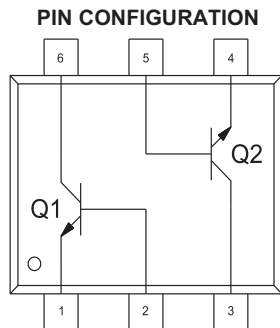
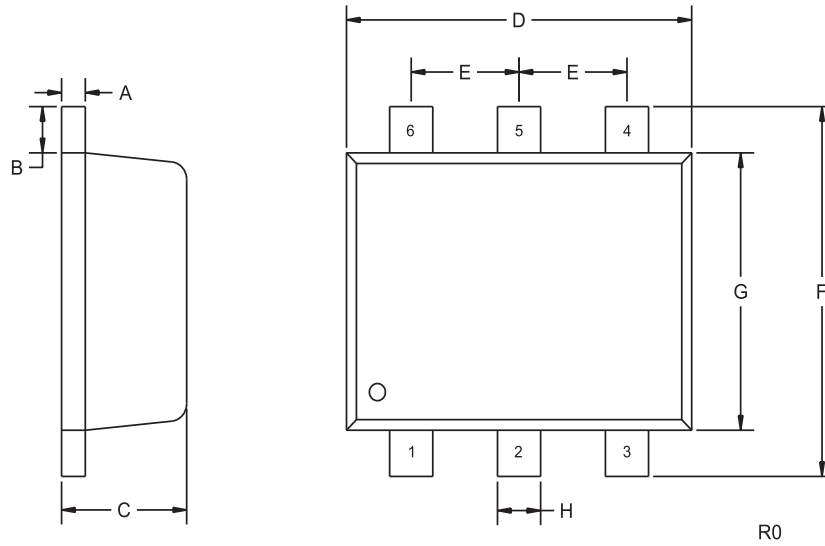
R1 (20-January 2010)

CMLT8099

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SOT-563 CASE - MECHANICAL OUTLINE



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.004	0.007	0.10	0.18
B	0.008		0.20	
C	0.022	0.024	0.56	0.60
D	0.059	0.067	1.50	1.70
E	0.020		0.50	
F	0.061	0.067	1.55	1.70
G	0.047		1.20	
H	0.006	0.012	0.15	0.30

SOT-563 (REV: R0)

LEAD CODE:

- 1) Emitter Q1
- 2) Base Q1
- 3) Collector Q1
- 4) Emitter Q2
- 5) Base Q2
- 6) Collector Q2

MARKING CODE: C89

R1 (20-January 2010)

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